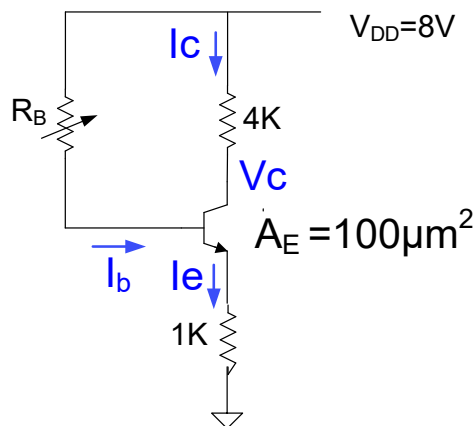


EE 330
Homework 8
Spring 2019 (Due Friday March 8th)

Unless stated to the contrary, assume all MOS transistors have model parameters $\mu_n C_{OX}=300\mu A/V^2$, $V_{Tn}=0.5V$, $\mu_n/\mu_p=4$, $V_{Tp}=-0.5V$, $C_{OX}=4fF/\mu^2$, $\lambda=0$, $\gamma=0$, and all BJT transistors have model parameters $J_S A=10^{-12}A$, $\beta_n=100$, and $\beta_p=30$.

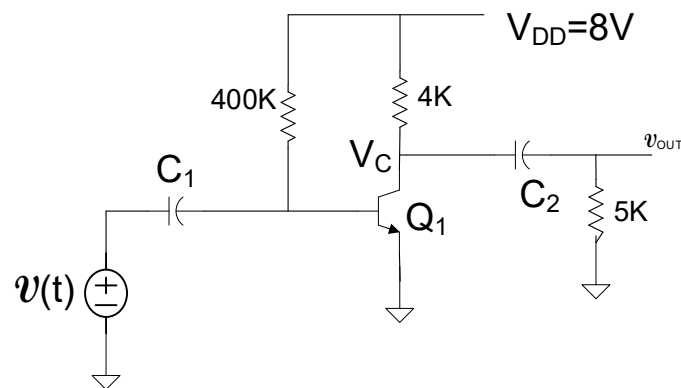
Problem 1 The following circuit was constructed for measuring the β of the bipolar transistor. To obtain the β , the resistor R_B was adjusted so that the current I_c was precisely 1.000mA. The current I_c was then measured to be 1.050mA. From these measurements the parameter α of the transistor was obtained and then β was calculated using the well-known relationship between α and β .

- What is the value of β for the transistor?
- What would be the worst-case error (in percent) in measuring the β of the transistor using this approach if the current measurements were only accurate to $\pm 1\%$?

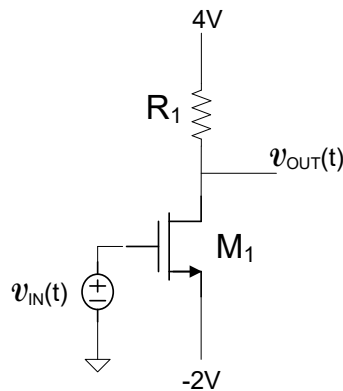


Problem 2 As an alternative to measuring β in the circuit for the previous problem (assuming β is the value determined in part a) of the previous problem), the currents I_b and I_c were measured. What would be the worst-case error (in percent) in measuring the β of the transistor using this alternative approach if the current measurements of I_b and I_c were only accurate to $\pm 0.25\%$?

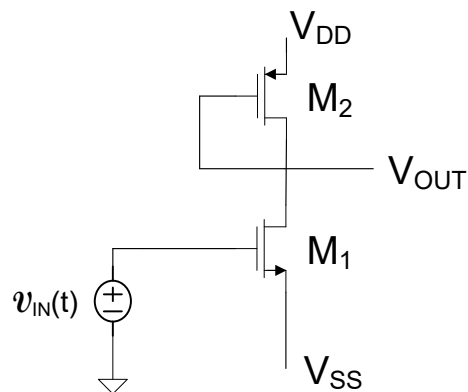
Problem 3 Assume the capacitors are very large. Determine the quiescent value of V_C and V_{OUT}



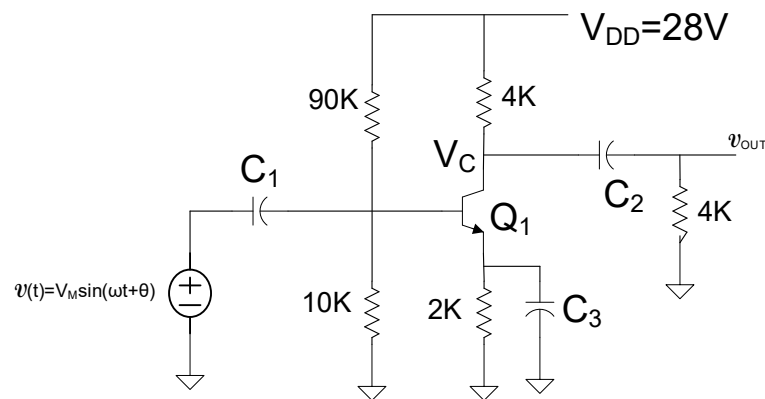
Problem 4 Determine the maximum value of R_1 that will keep M_1 in saturation. M_1 has dimensions $W=8\mu$ and $L=2\mu$. Assume the magnitude of the input is arbitrarily small.



Problem 5 Consider the following circuit. Determine the quiescent output voltage if $V_{DD}=2V$, $V_{SS}=-2V$, $W_1=10\mu$, $L_1=2\mu$, $W_2=50\mu$ and $L_2=1\mu$. Assume the magnitude of the input is arbitrarily small.

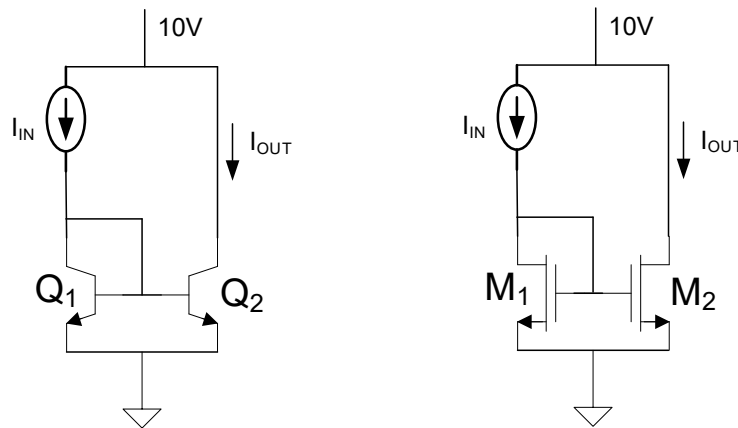


Problem 6 Assume the capacitors are all very large. Determine the quiescent value of V_C and V_{OUT}



Problem 7 Consider the two circuits shown.

- Determine the output current for the bipolar circuit if $A_{E1}=200\mu^2$ and $A_{E2}=1000\mu^2$ and $I_{IN}=1.5\text{mA}$. Assume β is very large.
- Determine the output current for the MOS circuit if $W_1/L_1=5$ and $W_2/L_2=20$ and $I_{IN}=1.5\text{mA}$.



Problem 8 Express the output current for the bipolar circuit in terms of the input current and the emitter areas for the circuit of Problem 9. Assume β is very large. Also express the output current for the MOS circuit in terms of the input current and the “W/L” ratios for the circuit of Problem 9. What conclusion can be drawn about the usefulness of these structures?

Problem 9 Use the D-flip flop you created in the previous homework to create a 4-bit register with an enable input that turns it on or off depending on its level. Show your Verilog code, testbench, and waveform output.

Note: Enable can be implement on the individual flip flop level or on the register level.